Unit in mm

TOSHIBA DUPER FAST RECOVERY RECTIFIER SILICON DIFFUSED TYPE

1 R 5 G U 4 1

SWITCHING TYPE POWER SUPPLY APPLICATIONS

• Repetitive Peak Reverse Voltage : V_{RRM}=400V

• Average Forward Current : I_{F (AV)}=1.5A (Ta=25°C)

ullet Very Fast Reverse-Recovery Time : $t_{rr} = 100$ ns

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	400	V	
Average Forward Current	I _{F (AV)}	1.5		
Peak One Cycle Surge Forward	Trons	60 (50Hz)	A	
Current (Non-Repetitive)	IFSM	66 (60Hz)		
Junction Temperature	T_{j}	-40~150	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~150	$^{\circ}\mathrm{C}$	

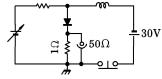
1. ANODE 2. CATHODE JEDEC — EIAJ — TOSHIBA 3-4B1A

Weight: 0.47g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

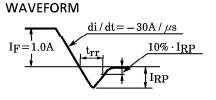
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$v_{ m FM}$	I _{FM} =1.5A	_	_	1.2	V
Repetitive Peak Reverse Current	${ m I}_{ m RRM}$	$V_{ m RRM} = 400 V$	_		50	μ A
Reverse Recovery Time (Note 1)	${ m t_{rr}}$	$I_{F}=1A$, di/dt=-30A/ μ s	_	_	100	ns
Forward Recovery Time (Note 2)	${ m t_{fr}}$	$I_{ m F}$ = 1.0A	_		200	ns
Thermal Resistance (Note 3)	$R_{ ext{th }(j-a)}$	Junction to Ambient	_	_	68	°C/W
Thermal Resistance (Note 3)	$R_{ ext{th }(j-\ell)}$	Junction to Lead	_	_	30	°C/W

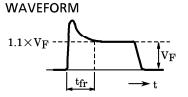
Note 1: trr TEST CIRCUIT



30V

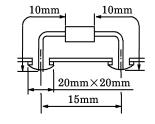
INPUT ❖





Note 2: t_{fr} TEST CIRCUIT

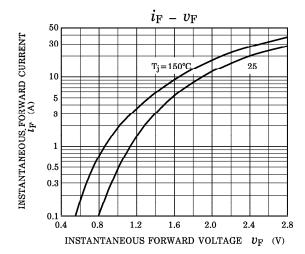
OUTPUT

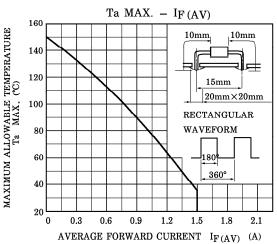


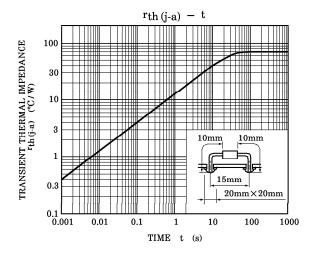
Note 3: THERMAL RESISTANCE

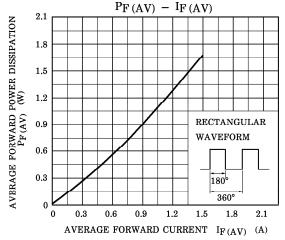
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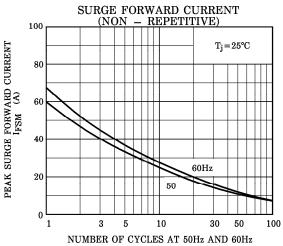
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